



FCX1151A

#### -40V PNP POWER TRANSISTOR IN SOT89

### **Features**

- BV<sub>CEO</sub> > -40V
- I<sub>C</sub> = -3A High Continuous Current
- I<sub>CM</sub> = -5A Peak Pulse Current
- Very Low V<sub>CE(sat)</sub> < -220mV at -1A</li>
- R<sub>CE(sat)</sub> = 66mΩ at -3A
- P<sub>D</sub> = 2W
- Complimentary Part FCX1051A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Applications**

- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC-DC Modules
- · Backlight Inverters
- Power Switches
- MOSFET Gate Drivers

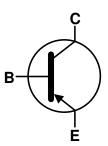
### **Mechanical Data**

Case: SOT89

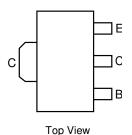
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.052 grams (Approximate)







Device Symbol



Pin-Out

### Ordering Information (Note 4)

| - 1 |             |            |         |                    |                 |                   |
|-----|-------------|------------|---------|--------------------|-----------------|-------------------|
|     | Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity Per Reel |
|     | FCX1151ATA  | AFC-Q101   | 151     | 7                  | 12              | 1 000             |

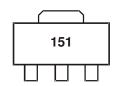
Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

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- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



151 = Product Type Marking Code



# **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | -45   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | -40   | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | -5    | V    |
| Continuous Collector Current | I <sub>C</sub>   | -3    | Α    |
| Peak Pulse Current           | I <sub>CM</sub>  | -5    | Α    |
| Base Current                 | I <sub>B</sub>   | -500  | mA   |

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                              | Symbol                            | Value           | Unit |      |  |
|---------------------------------------------|-----------------------------------|-----------------|------|------|--|
|                                             | (Note 5)                          |                 | 1    |      |  |
| Power Dissipation                           | (Note 6)                          | $P_{D}$         | 1.6  | W    |  |
|                                             | (Note 7)                          |                 | 2.0  |      |  |
|                                             | (Note 5)                          |                 | 125  |      |  |
| Thermal Resistance, Junction to Ambient Air | (Note 6)                          | $R_{\theta JA}$ | 78   | °C/W |  |
|                                             | (Note 7)                          |                 | 62.5 |      |  |
| Thermal Resistance, Junction to Lead        | (Note 8)                          | $R_{	heta JL}$  | 3.6  | °C/W |  |
| Operating and Storage Temperature Range     | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150     | °C   |      |  |

## ESD Ratings (Note 9)

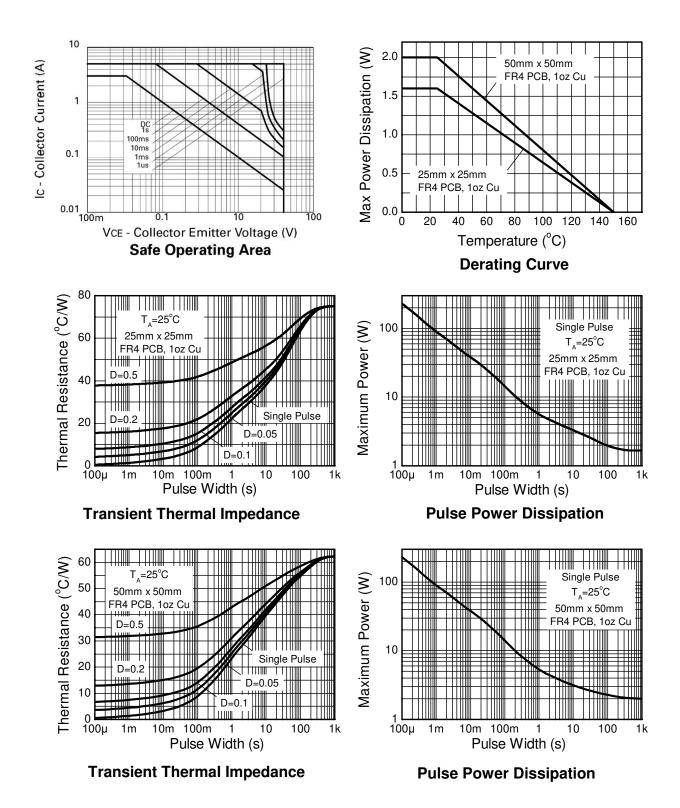
| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--------------------------------------------|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | С           |

Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
  9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

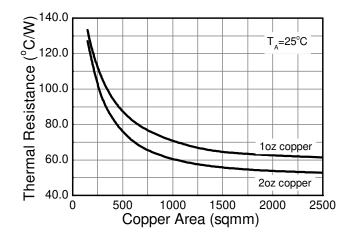


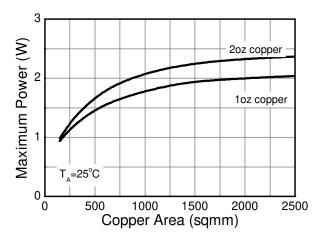
## **Thermal Characteristics and Derating Information**





# Thermal Characteristics and Derating Information (Cont.)







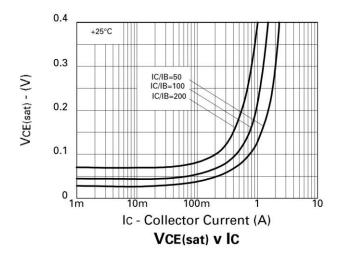
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

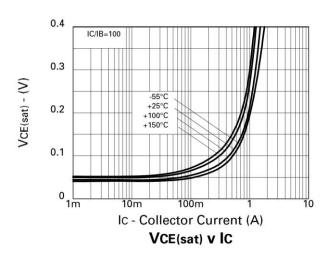
| Characteristic                                 | Symbol               | Min                      | Тур                            | Max                         | Unit | Test Condition                                                                                                                                                                                                                                                               |
|------------------------------------------------|----------------------|--------------------------|--------------------------------|-----------------------------|------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Collector-Base Breakdown Voltage               | BV <sub>CBO</sub>    | -45                      | _                              | _                           | V    | $I_C = -100\mu A$                                                                                                                                                                                                                                                            |
| Collector-Emitter Breakdown Voltage            | BV <sub>CES</sub>    | -40                      | _                              | _                           | V    | I <sub>C</sub> = -100μA                                                                                                                                                                                                                                                      |
| Collector-Emitter Breakdown Voltage (Note 10)  | BV <sub>CEO</sub>    | -40                      | _                              | _                           | V    | I <sub>C</sub> = -10mA                                                                                                                                                                                                                                                       |
| Collector-Emitter Breakdown Voltage            | BV <sub>CEV</sub>    | -40                      | _                              | _                           | V    | $I_C = -100 \mu A, V_{EB} = 1 V$                                                                                                                                                                                                                                             |
| Emitter-Base Breakdown Voltage                 | BV <sub>EBO</sub>    | -7                       | _                              | _                           | V    | $I_E = -100 \mu A$                                                                                                                                                                                                                                                           |
| Collector Cutoff Current                       | I <sub>CBO</sub>     | _                        | -0.3                           | -100                        | nA   | V <sub>CB</sub> = -36V                                                                                                                                                                                                                                                       |
| Collector Cutoff Current                       | I <sub>CES</sub>     | _                        | -0.3                           | -100                        | nA   | V <sub>CES</sub> = -32V                                                                                                                                                                                                                                                      |
| Emitter Cutoff Current                         | I <sub>EBO</sub>     | _                        | -0.3                           | -100                        | nA   | V <sub>EB</sub> = -4V                                                                                                                                                                                                                                                        |
| DC Current Transfer Static Ratio (Note 10)     | h <sub>FE</sub>      | 270<br>250<br>180<br>100 | 450<br>400<br>300<br>190<br>45 | -<br>800<br>-<br>-<br>-     | _    | $\begin{split} I_{C} &= -10 \text{mA}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -0.5 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -2 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -3 \text{A}, \ V_{CE} = -2 \text{V} \\ I_{C} &= -5 \text{A}, \ V_{CE} = -2 \text{V} \end{split}$ |
| Collector-Emitter Saturation Voltage (Note 10) | V <sub>CE(sat)</sub> | _                        | -60<br>-120<br>-140<br>-200    | -90<br>-180<br>-220<br>-300 | mV   | $I_{C} = -0.1A$ , $I_{B} = -1mA$<br>$I_{C} = -0.5A$ , $I_{B} = -5mA$<br>$I_{C} = -1A$ , $I_{B} = -20mA$<br>$I_{C} = -3A$ , $I_{B} = -250mA$                                                                                                                                  |
| Base-Emitter Saturation Voltage (Note 10)      | V <sub>BE(sat)</sub> | _                        | -985                           | -1050                       | mV   | I <sub>C</sub> = -3A, I <sub>B</sub> = -250mA                                                                                                                                                                                                                                |
| Base-Emitter Turn-on Voltage (Note 10)         | V <sub>BE(on)</sub>  | _                        | -850                           | -950                        | mV   | I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V                                                                                                                                                                                                                                  |
| Transitional Frequency                         | f <sub>T</sub>       | _                        | 145                            | _                           | MHz  | I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V,<br>f = 50MHz                                                                                                                                                                                                                 |
| Output Capacitance                             | C <sub>obo</sub>     | _                        | 40                             | _                           | pF   | V <sub>CB</sub> = -10V, f = 1MHz                                                                                                                                                                                                                                             |
| Cuitabina Tima                                 | t <sub>on</sub>      | _                        | 170                            | _                           | ns   | V <sub>CC</sub> = -30V, I <sub>C</sub> = -2A,                                                                                                                                                                                                                                |
| Switching Time                                 | t <sub>off</sub>     | _                        | 460                            | _                           | ns   | $I_{B1} = I_{B2} = \pm 20 \text{mA}$                                                                                                                                                                                                                                         |

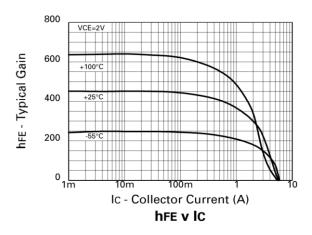
Note: 10. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .

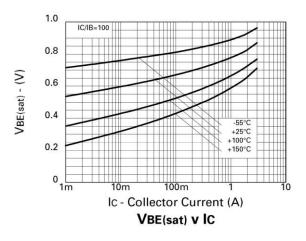


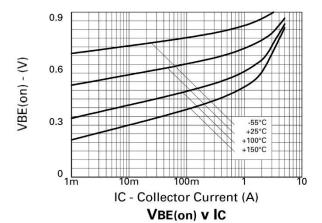
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)









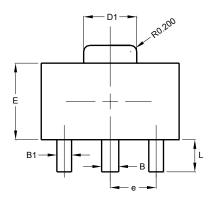


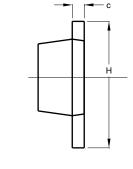


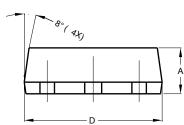
# **Package Outline Dimensions**

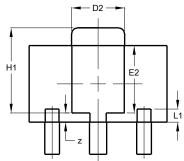
Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT89







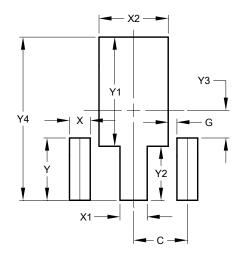


| SOT89                |       |       |       |  |  |
|----------------------|-------|-------|-------|--|--|
| Dim                  | Min   | Max   | Тур   |  |  |
| Α                    | 1.40  | 1.60  | 1.50  |  |  |
| В                    | 0.50  | 0.62  | 0.56  |  |  |
| B1                   | 0.42  | 0.54  | 0.48  |  |  |
| С                    | 0.35  | 0.43  | 0.38  |  |  |
| D                    | 4.40  | 4.60  | 4.50  |  |  |
| D1                   | 1.62  | 1.83  | 1.733 |  |  |
| D2                   | 1.61  | 1.81  | 1.71  |  |  |
| Е                    | 2.40  | 2.60  | 2.50  |  |  |
| E2                   | 2.05  | 2.35  | 2.20  |  |  |
| е                    | -     | -     | 1.50  |  |  |
| Н                    | 3.95  | 4.25  | 4.10  |  |  |
| H1                   | 2.63  | 2.93  | 2.78  |  |  |
| L                    | 0.90  | 1.20  | 1.05  |  |  |
| L1                   | 0.327 | 0.527 | 0.427 |  |  |
| Z                    | 0.20  | 0.40  | 0.30  |  |  |
| All Dimensions in mm |       |       |       |  |  |

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT89



| Dimensions   | Value   |
|--------------|---------|
| פווטופוופווט | (in mm) |
| C            | 1.500   |
| G            | 0.244   |
| Х            | 0.580   |
| X1           | 0.760   |
| X2           | 1.933   |
| Υ            | 1.730   |
| Y1           | 3.030   |
| Y2           | 1.500   |
| Y3           | 0.770   |
| Y4           | 4.530   |



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